

# **TDA9503**

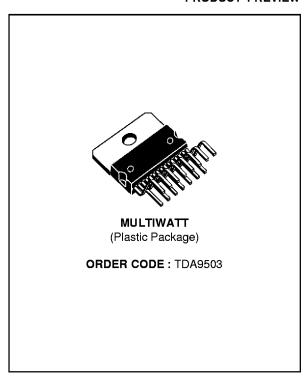
## TRIPLE HIGH VOLTAGE VIDEO AMPLIFIER

#### PRODUCT PREVIEW

■ TRIPLE CHANNELS VIDEO AMPLIFIER

BANDWIDTH: 40MHz TYPICALRISE AND FALL TIME: 9ns TYPICAL

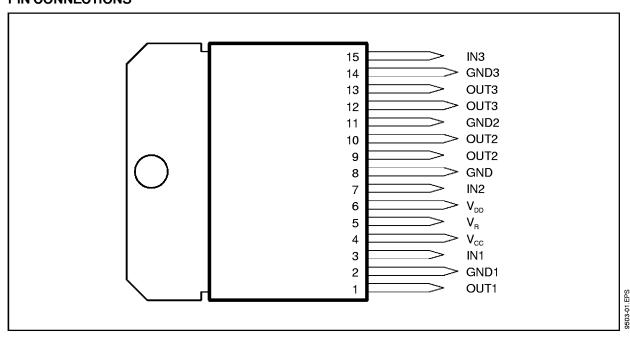
■ SUPPLY VOLTAGE: 90V



### **DESCRIPTION**

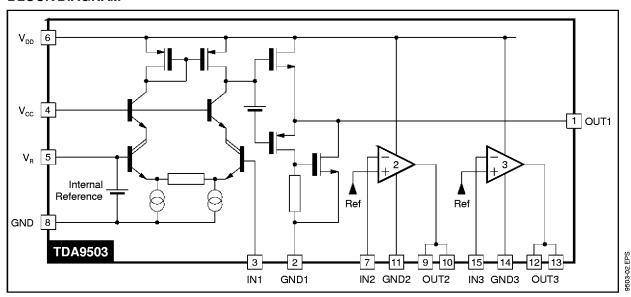
The TDA9503 includes 3 video amplifiers designed with a high voltage bipolar/CMOS/DMOS technology (BCD). It drives directly cathodes of a monitor and is protected against flashovers. It is available in multiwatt package.

## **PIN CONNECTIONS**



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### **BLOCK DIAGRAM**



## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>OUT</sub> , V <sub>DD</sub>	Supply High Voltage	100	V
Vcc	Supply Low Voltage	20	V
lop log	Output Current to V <sub>DD</sub> Output Current to Ground (pulsed < 50µs)	protected 80	mA
lj	Input Current	50	mA
Tj	Junction Temperature	150	°C
Toper	Operating Ambient Temperature	0, +70	°C
T <sub>stg</sub>	Storage Temperature	-20, +150	°C

## THERMAL DATA

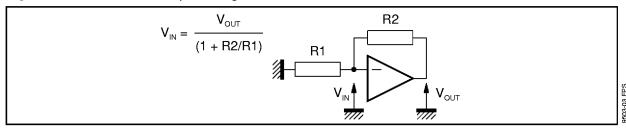
Symbol	Parameter	Value	Unit
R <sub>th (j-c)</sub>	Junction-Case Thermal Resistance Max.	3	°C/W
R <sub>th (j-a)</sub>	Junction-Ambient Thermal Resistance Typ.	35	°C/W

9503-02.TBL

## $\textbf{ELECTRICAL CHARACTERISTICS} \ (V_{CC} = 12V, V_{DD} = 90V, T_{amb} = 25^{o}C, unless \ otherwise \ specified)$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
$V_{DD}$	High Supply Voltage (Pin 6)		20		90	V
V <sub>CC</sub>	Low Supply Voltage (Pin 4)		10	12	15	V
I <sub>DD</sub>	High Voltage Supply Internal DC Current (without current due to the feedback network)	V <sub>OUT</sub> = 50V		24		mA
Icc	Low Voltage Supply Internal DC Current			20		mA
V <sub>R</sub>	Internal Reference	Measured on Pin 5		3.5		٧
$V_{IN}$	Typical Input Voltage	V <sub>OUT</sub> = 50V		3.8		٧
$dV_{IN}/dV_{CC}$	Drift of Input Voltage versus V <sub>CC</sub>				TBD	%
dV <sub>IN</sub> /dT	Drift of Input Voltage versus Temperature	See Figure 1			TBD	mV/°C
V <sub>SATH</sub>	High Output Saturation Voltage	I <sub>O</sub> = -60mA		V <sub>DD</sub> - 6.5		V
VSATL	Low Output Saturation Voltage	I <sub>O</sub> = 60mA		17		V
BW	Bandwidth at -3dB	$C_{LOAD}$ = 10pF, Rprotect = 200 $\Omega$ , $V_{OUT}$ = 50V, $\Delta V_{OUT}$ = 40V <sub>PP</sub> , Feedback gain = 20 See Figure 2		40		MHz
t <sub>R</sub> , t <sub>F</sub>	Rise and Fall Time	Measured between 10% & 90% of output pulse, $C_{LOAD} = 10pF$ , $Rprotect = 200\Omega$ , $V_{OUT} = 50V$ , $\Delta V_{OUT} = 40V_{PP}$		9		ns
Go	Open Loop Gain	V <sub>OUT</sub> = 50V		57		dB
I <sub>IB</sub>	Input Bias Current (Pin 1)	V <sub>OUT</sub> = 50V		10		μΑ
R <sub>IN</sub>	Input Resistance		TBD	200		kΩ
СТ	Crosstalk between Video channel	$\Delta V_{OUT} = 20V_{PP}, V_{IN} = 1V_{PP},$ $f_{IN} = 1MHz$		TBD		dB

Figure 1 : Measurement of Input Voltage



#### TYPICAL APPLICATION

The TDA9503 is composed of different parts:

- A differential amplifier, the gain of which is fixed by external feedback resistors;
- An integrated voltage reference designed with a bandgap.

### PC board lay-out

The best performances of the high voltage video amplifier will be obtained only with a carefully designed PC board. Output to input capacitances are of particular importance.

For a single amplifier, the input-output capacitance, in parallel with the relatively high feedback resistance, leads to an integrator response. This parasitic capacitor has to be compensated by another capacitor connected in parallel on imput serial gain resistor. A well matched compensation allows to use the full bandwidth of the TDA9503. In other cases the system has an integrator response with lower bandwidth, or a differentiator response with too much ringing.

Figure 2: Typical Evaluation Schematic

A low parasitic capacitance (0.3pF) feedback resistor and HF isolated printed wires are necessary.

### Power dissipation

The power dissipation consists of a static part and a dynamic part. The static dissipation varies with the output voltage and the feedback resistor. The dynamic power dissipation increases with the pixel frequency.

For a signal frequency of 40MHz and  $40V_{PP}$  output signal, the typical power dissipation is about 2.3W, for  $V_{DD} = 90V$ .

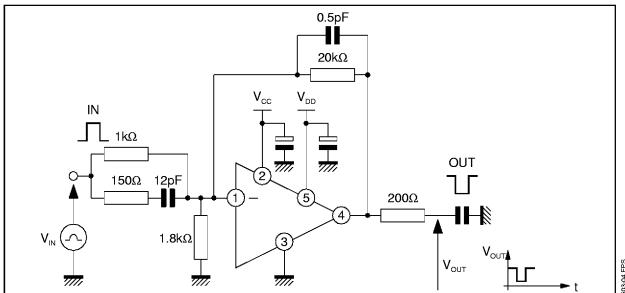
In first approximation, the dynamic dissipation is:

$$P_D = V_{DD} \times C_{LOAD} \times \Delta V_{OUT} \times f \times 3$$
 and the total dissipation is :

P =  $V_{DD} \times C_{LOAD} \times \Delta V_{OUT} \times f \times 3 + V_{DD} \times I_{DD}$ 

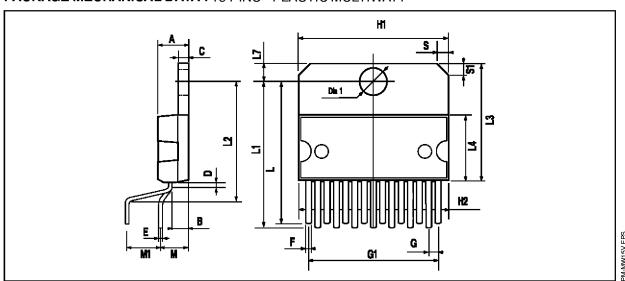
+ Vcc x lcc - (V<sub>DD</sub> - 
$$\overline{V_{OUT}}$$
) x  $\frac{\overline{V_{OUT}}}{R_{FEEDBACK}}$  x 3

with f = pixel frequency



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### PACKAGE MECHANICAL DATA: 15 PINS - PLASTIC MULTIWATT



Dimensions		Millimeters			Inches	
Dimensions	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			5			0.197
В			2.65			0.104
С			1.6			0.063
D		1			0.039	
E	0.49		0.55	0.019		0.022
F	0.66		0.75	0.026		0.030
G	1.02	1.27	1.52	0.040	0.050	0.060
G1	17.53	17.78	18.03	0.690	0.700	0.710
H1	19.6			0.772		
H2			20.2			0.795
L	21.9	22.2	22.5	0.862	0.874	0.886
L1	21.7	22.1	22.5	0.854	0.870	0.886
L2	17.65		18.1	0.695		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
М	4.25	4.55	4.85	0.167	0.179	0.191
M1	4.63	5.08	5.53	0.182	0.200	0.218
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia. 1	3.65		3.85	0.144		0.152

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